

# First-principles calculation of **many-body** effects in **graphene**

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# Acknowledgments

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Prof. Steven G. Louie (UC Berkeley and LBNL)  
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## Discussions

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Prof. Sohrab Ismail-Beigi (Yale University)  
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Dr. Eli Rotenberg (ALS)  
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# Outline

- Preliminaries
  - Graphene
  - Electron self energy / ARPES
  - Migdal approximation
  - *GW* approximation
- Electron self energy in graphene
  - Contribution from electron-phonon (e-ph) interactions
  - Contribution from electron-electron (e-e) interactions
  - Combining the effects of e-ph and e-e interactions

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# Graphene

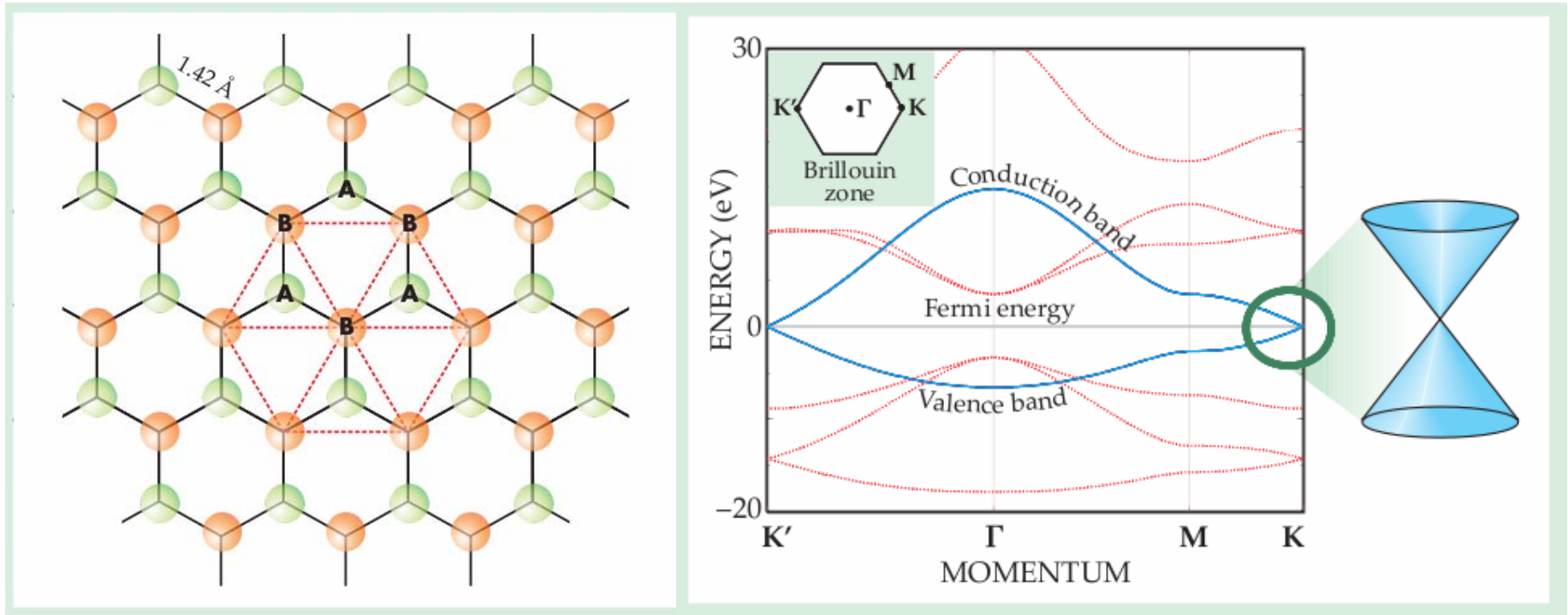
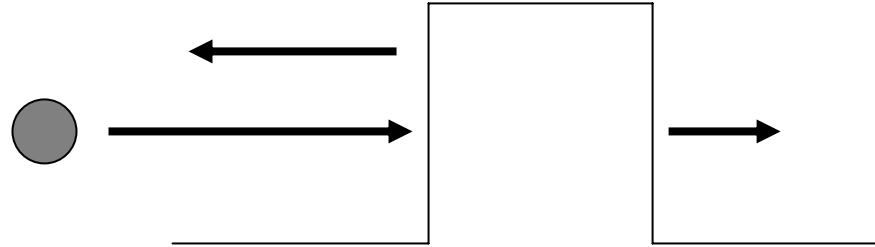


Figure: Geim and McDonald, Phys. Today (2008)

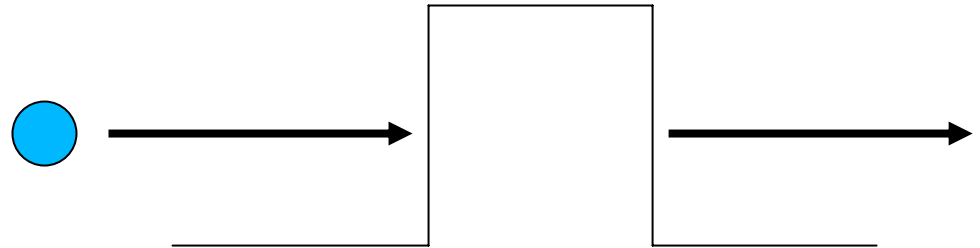
Charge carriers in graphene are **2D massless Dirac fermions**

# Klein tunneling in graphene

Conventional 2DEG



Graphene

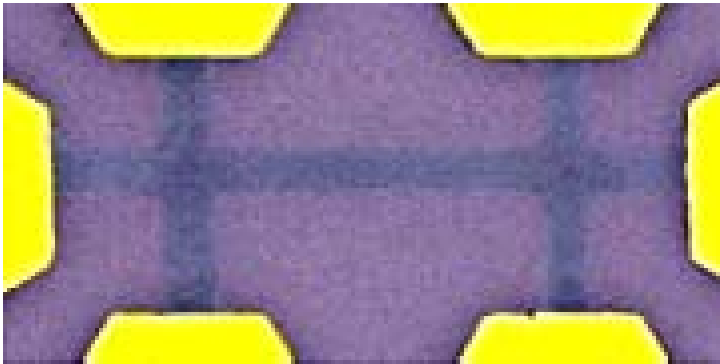


The most spectacular phenomenon of **2D massless Dirac fermions**

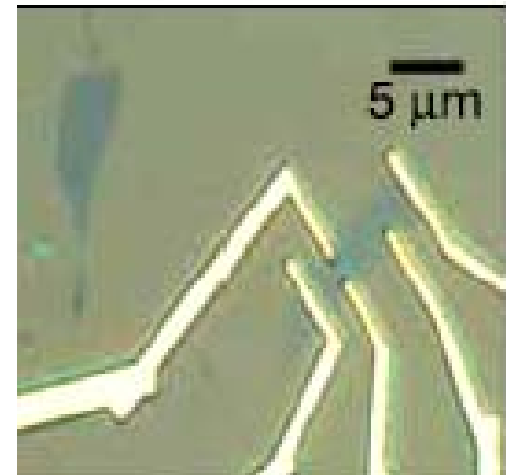
# Scotch tape separated graphene

Isolation of **single-layer graphene** and  
observation of **new integer quantum Hall effect**

A. K. Geim Group at Manchester  
K. S. Novoselov *et al*, Nature **438**, 197 (2005)



P. Kim Group at Columbia  
Y. Zhang *et al*, Nature **438**, 201 (2005)

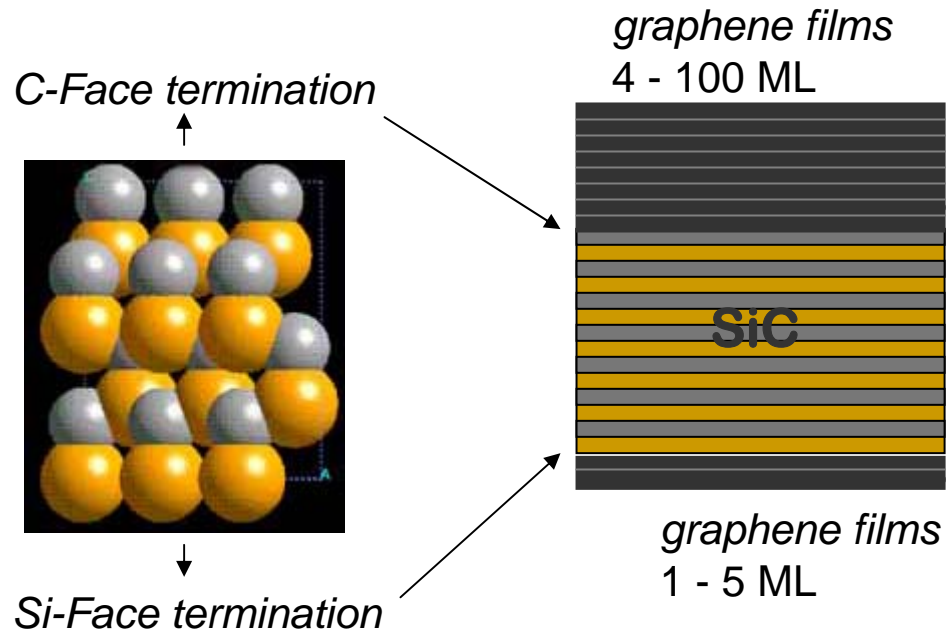


# Epitaxial growth of graphene layers on SiC

Thermal decomposition of SiC at high temperature ( $>1400^{\circ}\text{C}$ )

→ Sublimation of Si

C. Berger *et al.*, *J Phys Chem B* 108, 19912 (2004)



**By controlling temperature, growth of 1 to ~100 graphene layers (tens of microns)**

(Slide courtesy of Walter de Heer)



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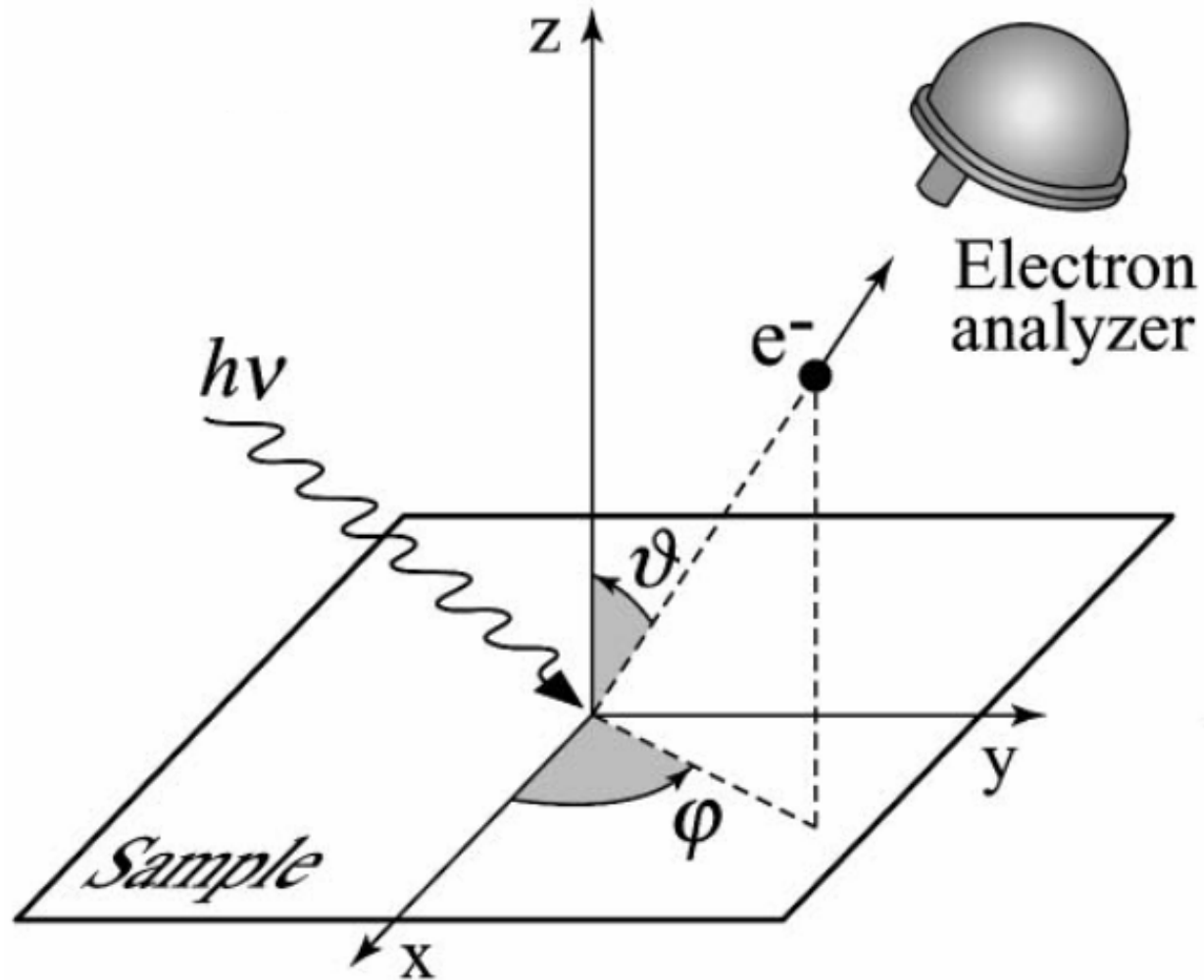
# Electron self energy due to many-body effects

$\Sigma_{\mathbf{k}}$  ← **Many-body effects:**  
e-e interactions (e-h pair generation, plasmon emission)  
e-ph interactions  
impurity scattering  
...

$$\varepsilon_{\mathbf{k}} = \varepsilon_{\mathbf{k}}^0 + \text{Re} \Sigma_{\mathbf{k}} \quad \text{Quasiparticle energy}$$

$$\tau_{\mathbf{k}} = \frac{\hbar}{2 \text{Im} \Sigma_{\mathbf{k}}} \quad \text{Quasiparticle lifetime}$$

# Angle-resolved photoemission spectroscopy (ARPES)



# Angle-resolved photoemission spectroscopy (ARPES)

$$I(\mathbf{k}, \omega, \hat{e}_\nu, h\nu) = I_0(\mathbf{k}, \omega, \hat{e}_\nu, h\nu) f_{\text{FD}}(\omega) A(\mathbf{k}, \omega)$$

$$A(\mathbf{k}, \omega) = \frac{2}{\pi} \frac{-\text{Im} \Sigma(\mathbf{k}, \omega)}{[\omega - \varepsilon_{\mathbf{k}} - \text{Re} \Sigma(\mathbf{k}, \omega)]^2 + [\text{Im} \Sigma(\mathbf{k}, \omega)]^2}$$

ARPES → electron self energy

## Width of the momentum distribution curve (MDC)

$$\varepsilon_{\mathbf{k}} = \hbar v_F k \quad (\text{graphene or doped cuprates})$$

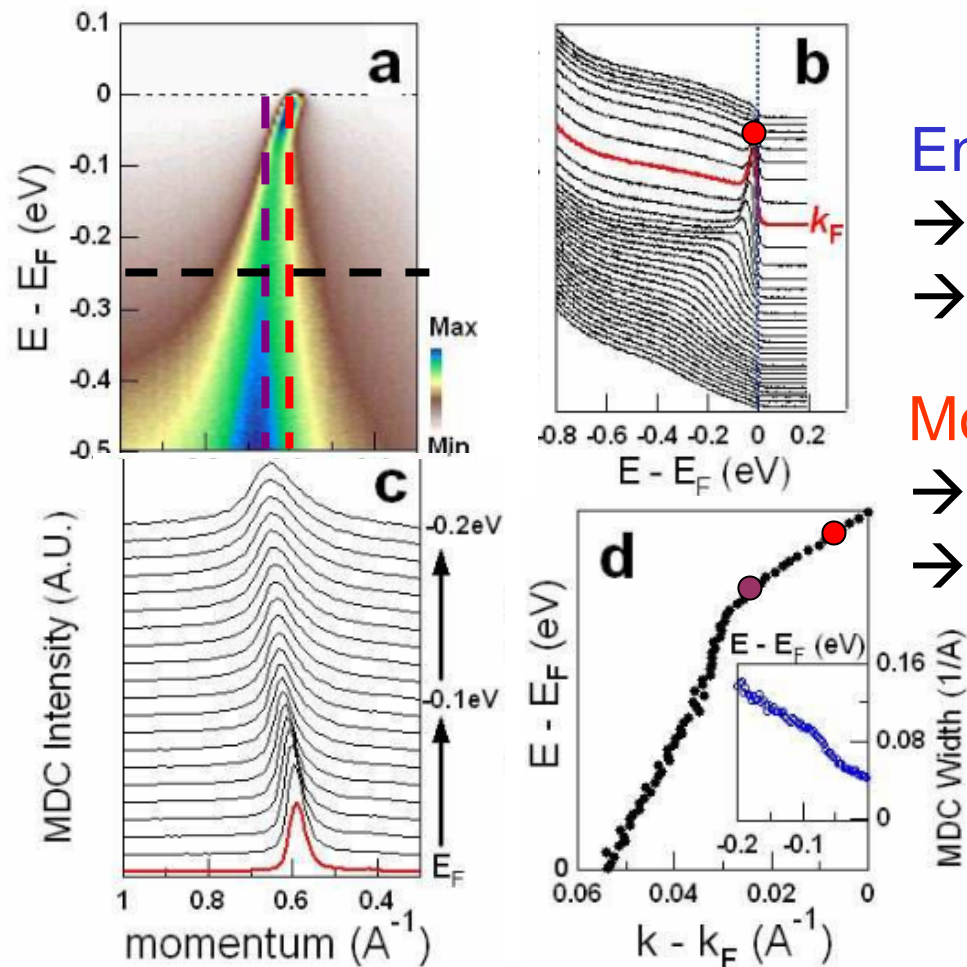
$$A(\mathbf{k}, \omega) = \frac{2}{\pi} \frac{-\text{Im} \Sigma(\mathbf{k}, \omega)}{[\omega - \hbar v_{\mathbf{k}} k - \text{Re} \Sigma(\mathbf{k}, \omega)]^2 + [\text{Im} \Sigma(\mathbf{k}, \omega)]^2}$$

$$\approx \frac{2}{\pi} \frac{-\text{Im} \Sigma(\omega)}{[\omega - \hbar v_{\mathbf{k}} k - \text{Re} \Sigma(\omega)]^2 + [\text{Im} \Sigma(\omega)]^2} \quad \text{Lorentzian of } k$$

$$\Delta k(\omega) = \text{FWHM} \approx 2 \times \frac{|\text{Im} \Sigma(\omega)|}{\hbar v_F}$$

Imaginary part of the self energy is proportional to the **MDC width** in graphene, to a good approximation.

# Angle-resolved photoemission spectroscopy (ARPES)

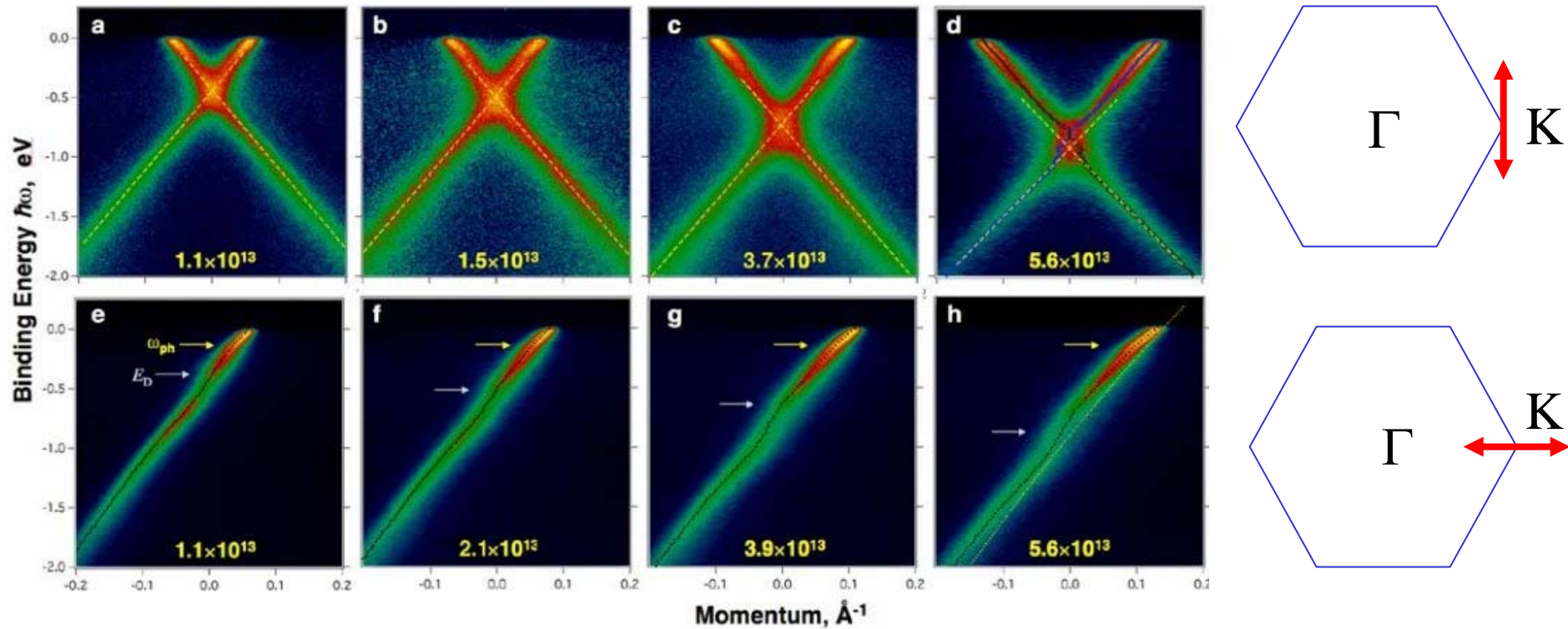


Energy distribution curve (EDC)  
→ Quasiparticle bandstructure  
→ Real part of the self energy

Momentum distribution curve (MDC)  
→ Width gives lifetime  
→ Imaginary part of the self energy

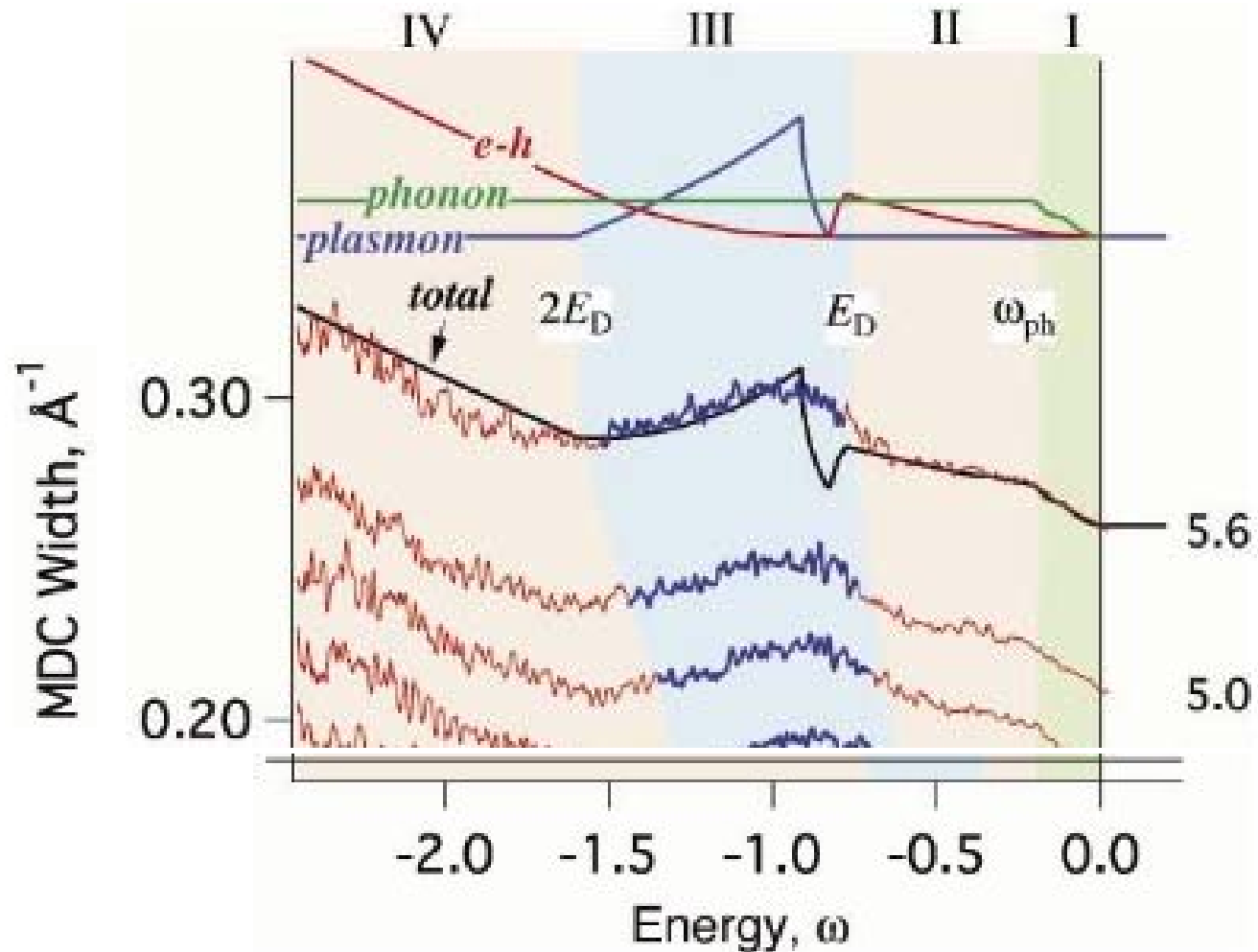
# Motivation

ARPES of epitaxial graphene on (0001) surface of SiC<sup>1</sup>



1) A. Bostwick, *et. al.*, Nature Physics **3**, 36 (2007)

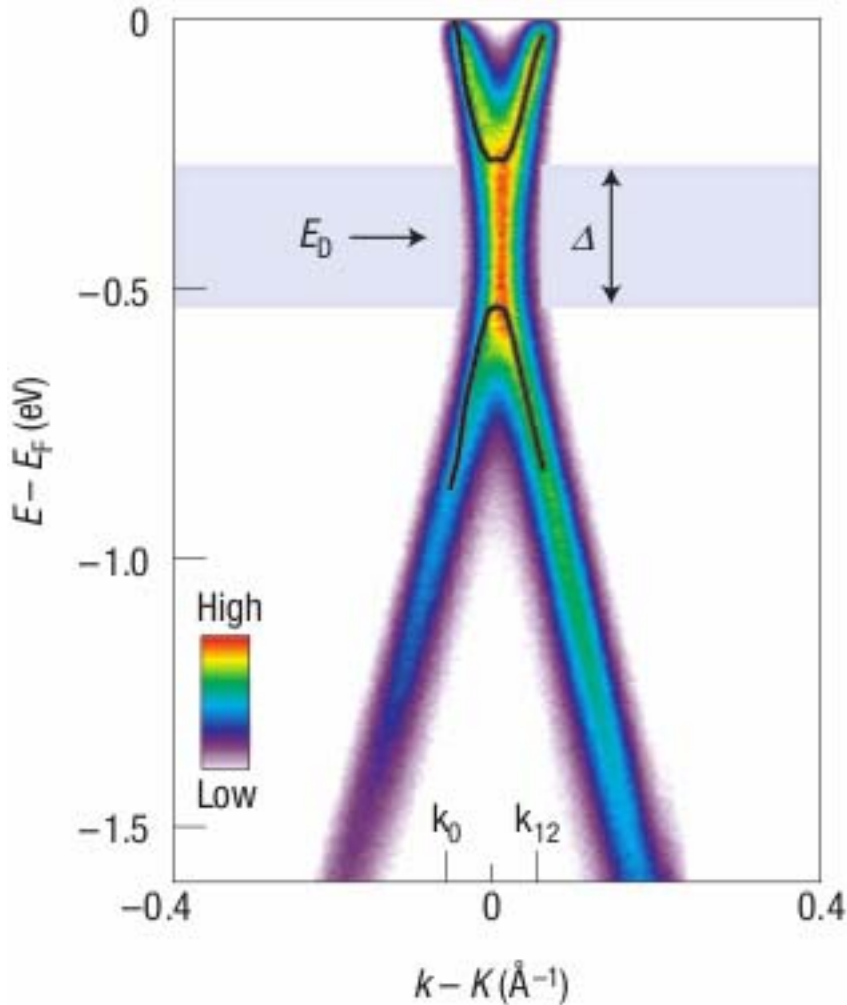
# Motivation



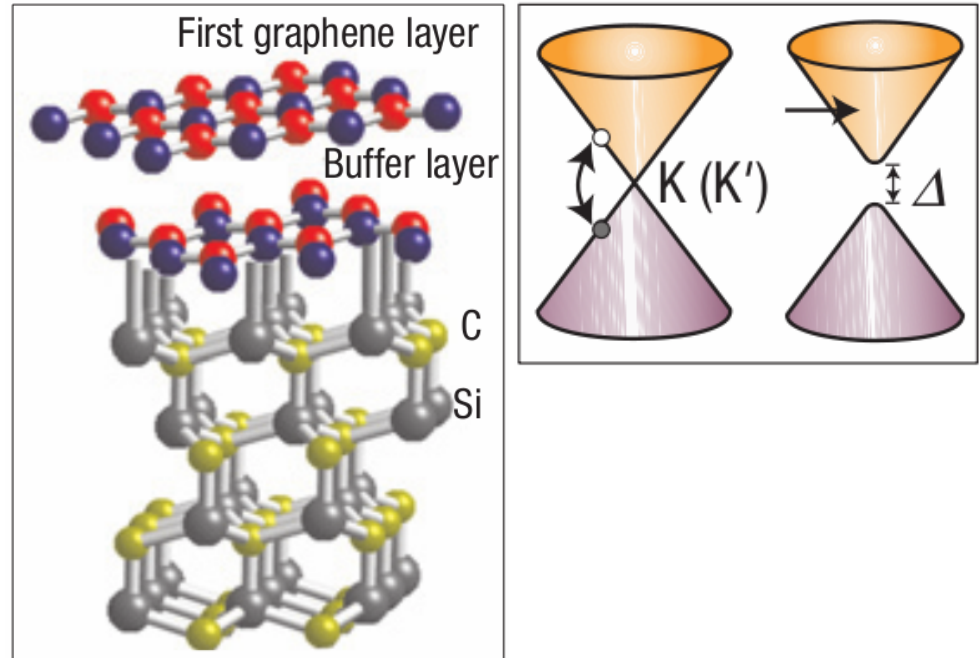
A. Bostwick, *et. al.*, Nature Physics **3**, 36 (2007).



# Motivation



## Substrate induced band gap



Important issue for applications

S.Y. Zhou, *et al.*, Nature Materials **6**, 770 (2007).

# Interpretation of the ARPES spectra of graphene

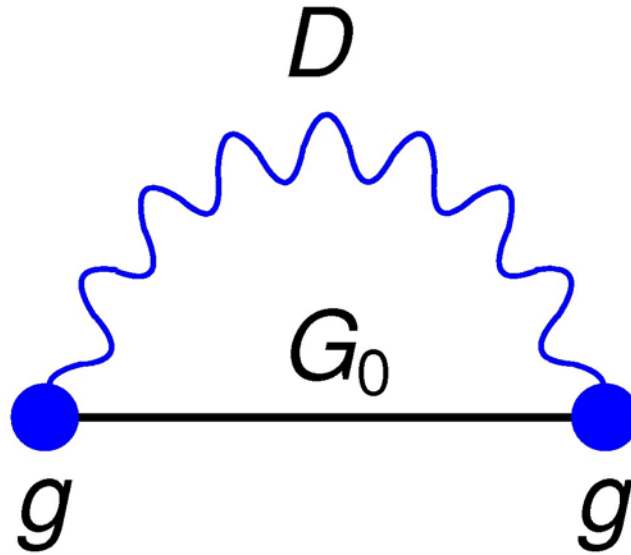
Q: Self-energy effects<sup>1</sup> or substrate induced band gap<sup>2</sup>?

- 1) A. Bostwick, *et. al.*, Nature Physics **3**, 36 (2007).
- 2) S.Y. Zhou, *et. al.*, Nature Materials **6**, 770 (2007).

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# Migdal approximation



$$\Sigma^{e\text{-ph}} = i g^2 D G_0$$

Electron self energy arising from e-ph interactions

# Electron self energy arising from e-ph interactions

- Step 1. DFT wavefunctions (plane-wave basis) and energy eigenvalues within **LDA** using *ab initio* pseudopotentials.<sup>1</sup>

$$\left[ -\frac{\nabla^2}{2} + V_{ion} + V_{Hartree} + V_{xc}^{LDA} \right] \psi_{nk} = E_{nk}^{LDA} \psi_{nk}$$

- Step 2. Phonon eigenmodes / frequencies / electron-phonon coupling within **DFPT**<sup>2</sup>

$$g_{n,n',\lambda}(\mathbf{k}, \mathbf{q}) = \sqrt{\frac{\hbar}{2M\omega_{\lambda,\mathbf{q}}}} \langle n, \mathbf{k} | \Delta V_{SCF}(\lambda, \mathbf{q}) | n', \mathbf{k} + \mathbf{q} \rangle$$

1) W. Kohn and L.J. Sham, Phys. Rev. **140**, A1133 (1965)

2) S. Baroni *et al.*, Rev. Mod. Phys. **73**, 515 (2001)

# Electron self energy arising from e-ph interactions

- Step 3. **Interpolation** of the above quantities for q points in a fine grid (**500 x 500 irreducible points**) using maximally localized Wannier functions.<sup>1-3</sup>
- Step 4. Self-energy of electron within **Migdal formalism**.<sup>4</sup>

$$\Sigma_n(\mathbf{k}, E) =$$

$$\sum_{n', \lambda} \int \frac{d^2 q}{A_{BZ}} g_{n, n', \lambda}(\mathbf{k}, \mathbf{q})^2 \left[ \frac{n_B(\omega_{\lambda, \mathbf{q}}) + 1 - n_F(\xi_{n', \mathbf{k} + \mathbf{q}})}{E - \xi_{n', \mathbf{k} + \mathbf{q}} - \omega_{\lambda, \mathbf{q}} + i\delta} + \frac{n_B(\omega_{\lambda, \mathbf{q}}) + n_F(\xi_{n', \mathbf{k} + \mathbf{q}})}{E - \xi_{n', \mathbf{k} + \mathbf{q}} + \omega_{\lambda, \mathbf{q}} + i\delta} \right]$$

1) N. Marzari and D. Vanderbilt, Phys. Rev. B **56**, 12847 (1997)

2) I. Souza, N. Marzari and D. Vanderbilt, Phys. Rev. B **65**, 035109 (2001)

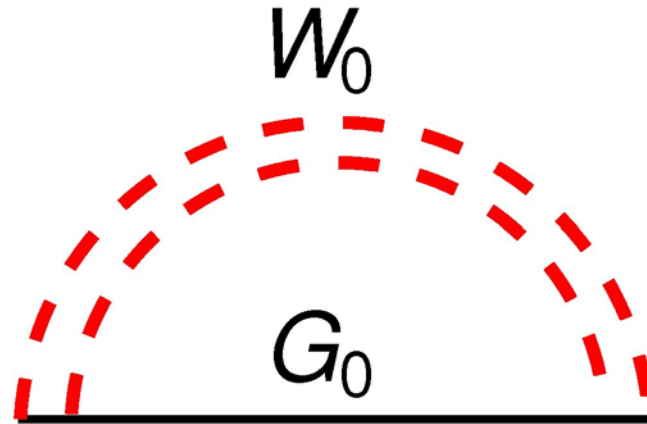
3) F. Giustino, M.L. Cohen and S.G. Louie, Phys. Rev. B **76**, 165108 (2007)

4) J.R. Schrieffer, Theory of Superconductivity (W.A.Benjamin, Inc., 1964)

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# GW approximation



$$\Sigma^{e-e} = i G_0 W_0$$

Electron self energy arising from e-e interactions



# Electron self energy arising from e-e interactions

- Step 1. Ground state calculation
  - DFT wavefunctions and eigenvalues within **LDA** using *ab initio* pseudopotentials. <sup>1</sup>

$$\left[ -\frac{\nabla^2}{2} + V_{ion} + V_{Hartree} + V_{xc}^{LDA} \right] \psi_{nk} = E_{nk}^{LDA} \psi_{nk}$$

- Step 2. QP self-energy within **GW Approximation** <sup>2</sup>

$$\left[ -\frac{\nabla^2}{2} + V_{ion} + V_{Hartree} + \Sigma(E_{nk}) \right] \psi_{nk} = E_{nk} \psi_{nk} \quad (\Sigma = iG_0W_0)$$

1) W. Kohn and L.J. Sham, Phys. Rev. **140**, A1133 (1965)

2) M.S. Hybertsen and S.G. Louie, Phys. Rev. B **34**, 5390 (1986)

# Electron self energy arising from e-e interactions

- GW calculations performed with BerkeleyGW code<sup>1</sup>.
- Full dynamical dielectric screening of graphene was calculated<sup>2</sup>.
- Substrate screening was modeled by<sup>3-4</sup>  $\epsilon_q(\omega) = \epsilon_{\text{eff}} - v_q P_q(\omega)$ .

$$\epsilon_{\text{eff}} = (1 + \epsilon_{\text{sub}}^{\infty}) / 2$$

$v_q$  bare Coulomb interaction

$P_q(\omega)$  polarizability of graphene

- 1) J. R. Deslippe et al., computer code BerkeleyGW (2009)
- 2) L. X. Benedict, C. D. Spataru, and S. G. Louie, PRB 66, 085116 (2002)
- 3) E. H. Hwang and S. Das Sarma, PRB 75, 205418 (2007)
- 4) M. Polini et al., PRB 77, 081411 (2008)

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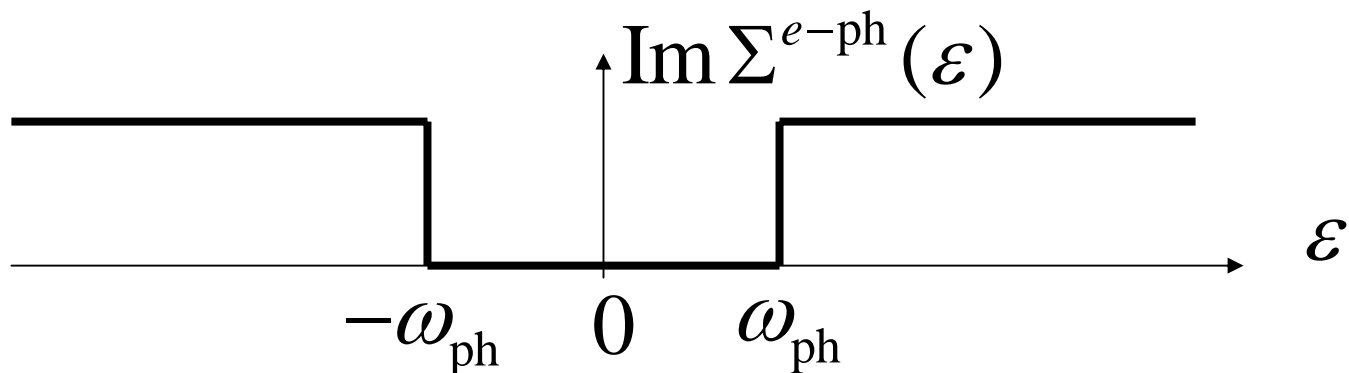
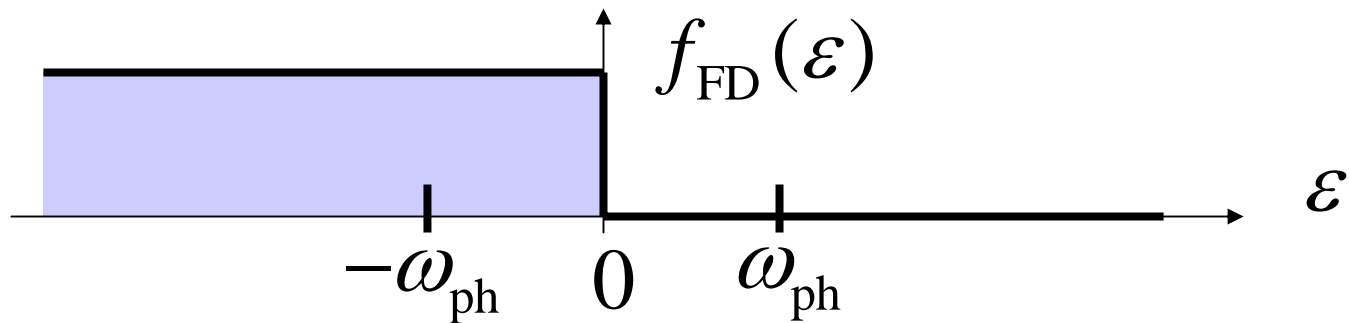
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# Imaginary part of the electron self energy (e-ph interactions)

Conventional metal:  $\text{Im } \Sigma^{e\text{-ph}}(\varepsilon)$

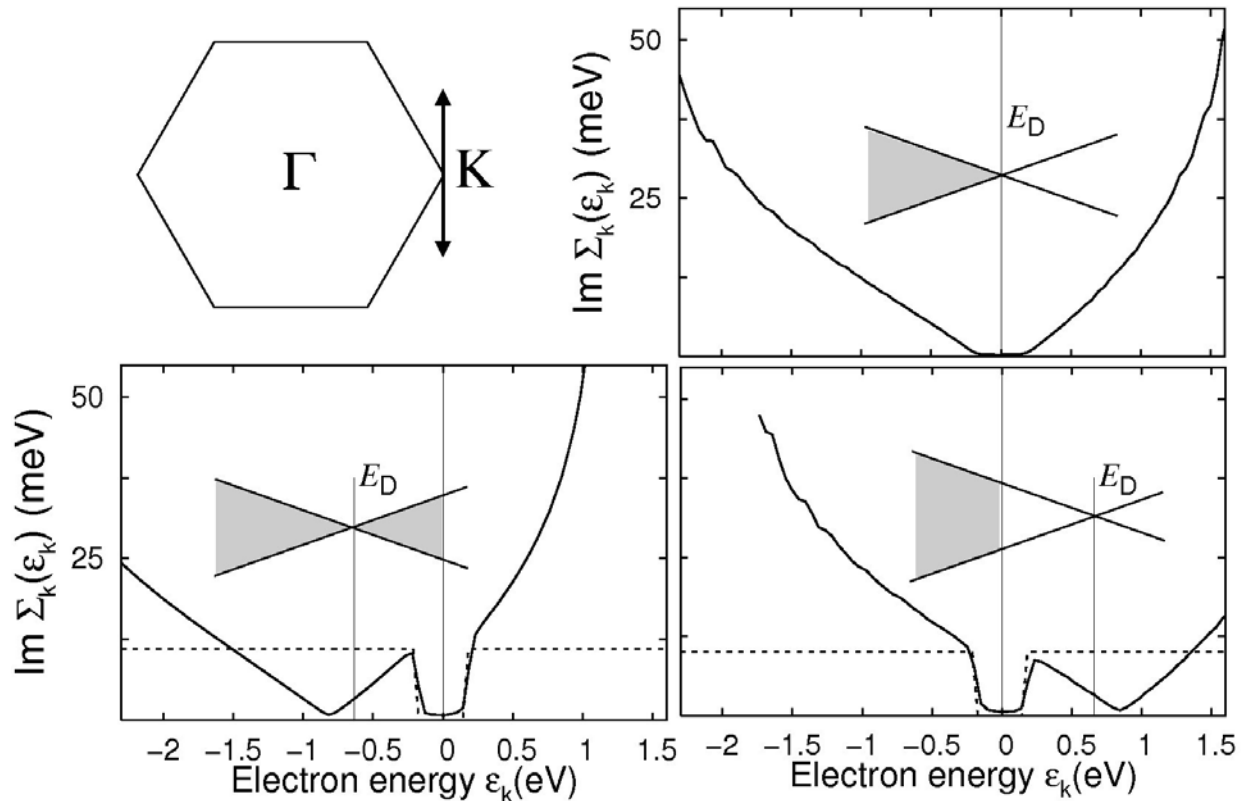
(1) Constant DOS near the Fermi level

(2) One effective optical phonon branch (Einstein phonon spectrum)



# Imaginary part of the electron self energy (e-ph interactions)

$\text{Im } \Sigma_{\mathbf{k}}^{e\text{-ph}}(\epsilon_{\mathbf{k}})$ 
 graphene  
 conventional metal

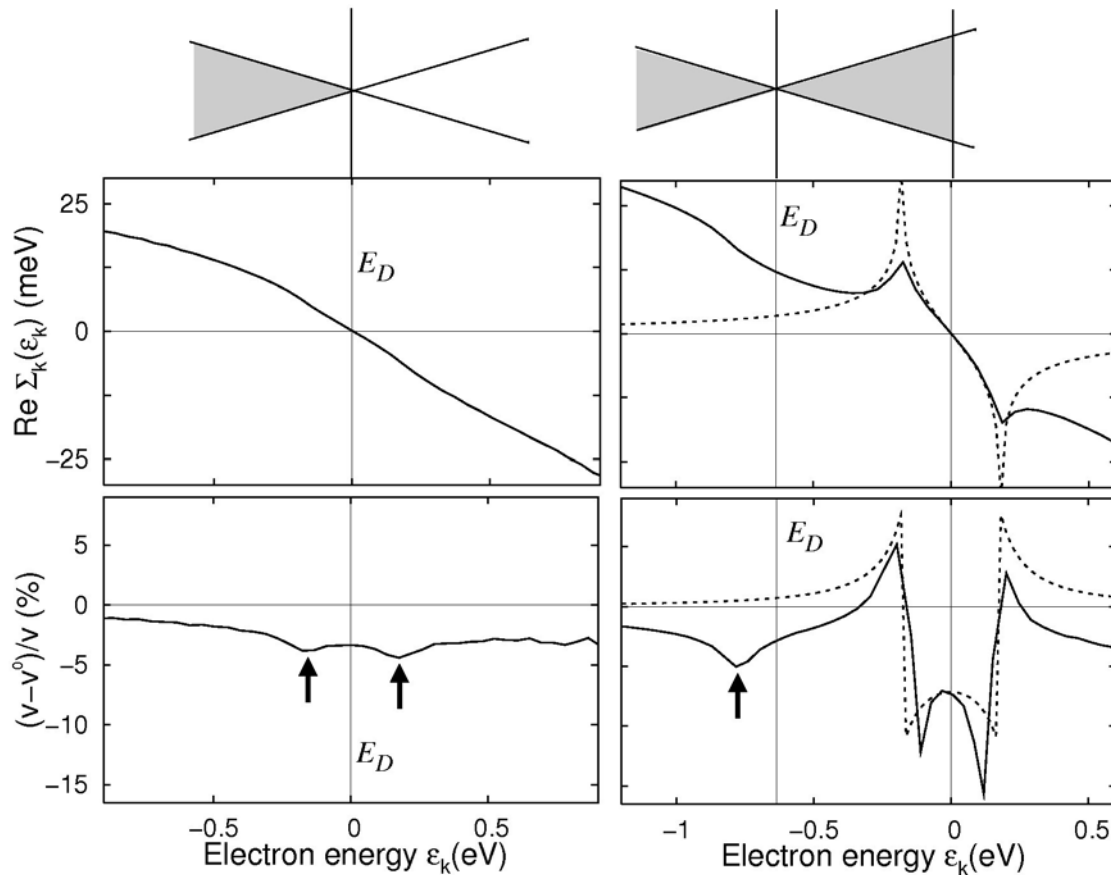


Imaginary part of the self energy reflects linear density of states in graphene.  
 Highest optical phonon branches ( $\sim 0.2$  eV) are dominant.

# Real part of the electron self energy (e-ph interactions)

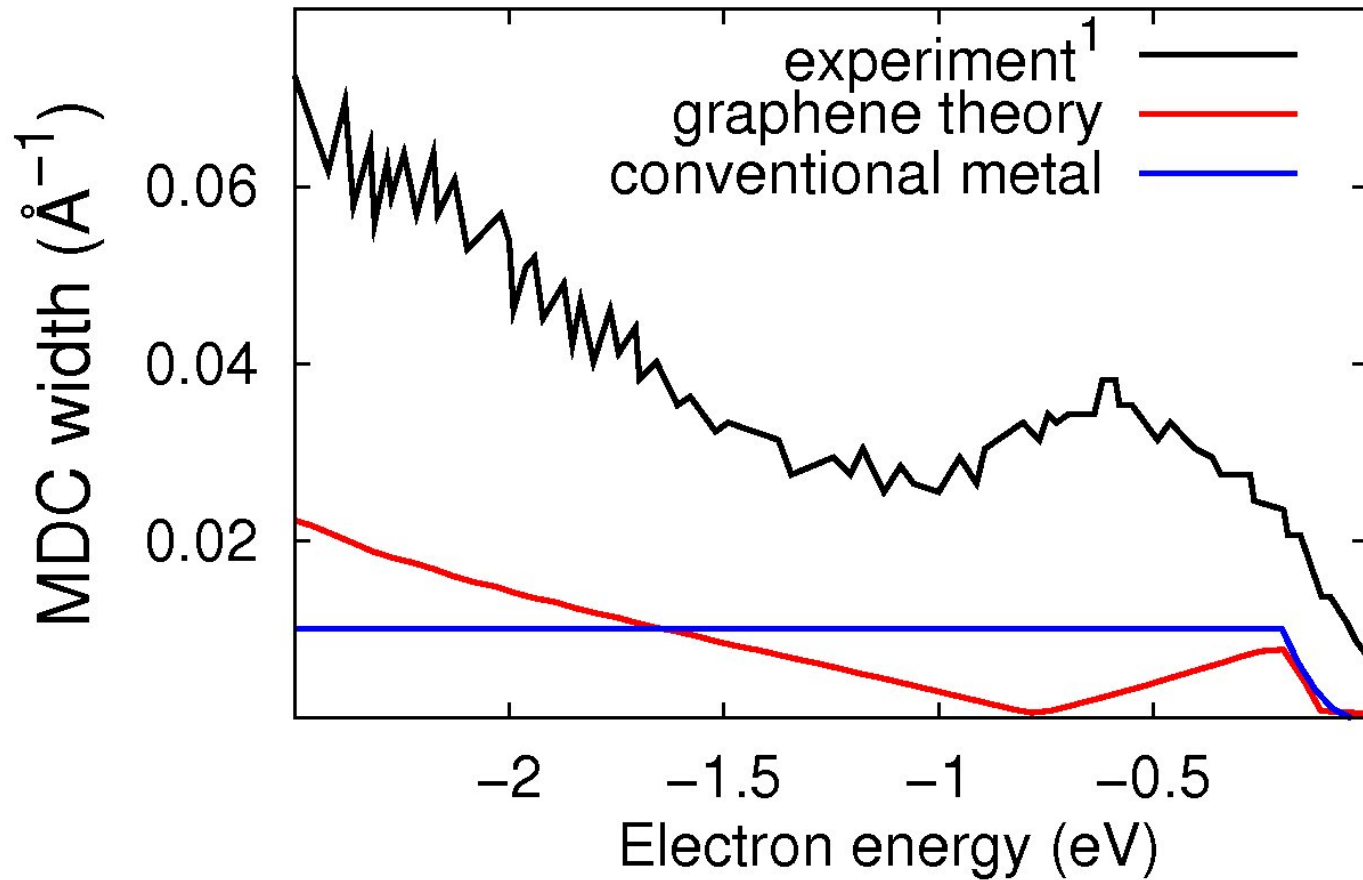
$$\text{Re } \Sigma_{\mathbf{k}}^{e\text{-ph}}(\epsilon_{\mathbf{k}})$$

graphene  
 conventional metal



The real part gives rise to 4%~8% reduction in the fermi velocity.

## Comparison with experiment (MDC width)



1) A. Bostwick et al., Nature Phys. 3, 36 (2007)

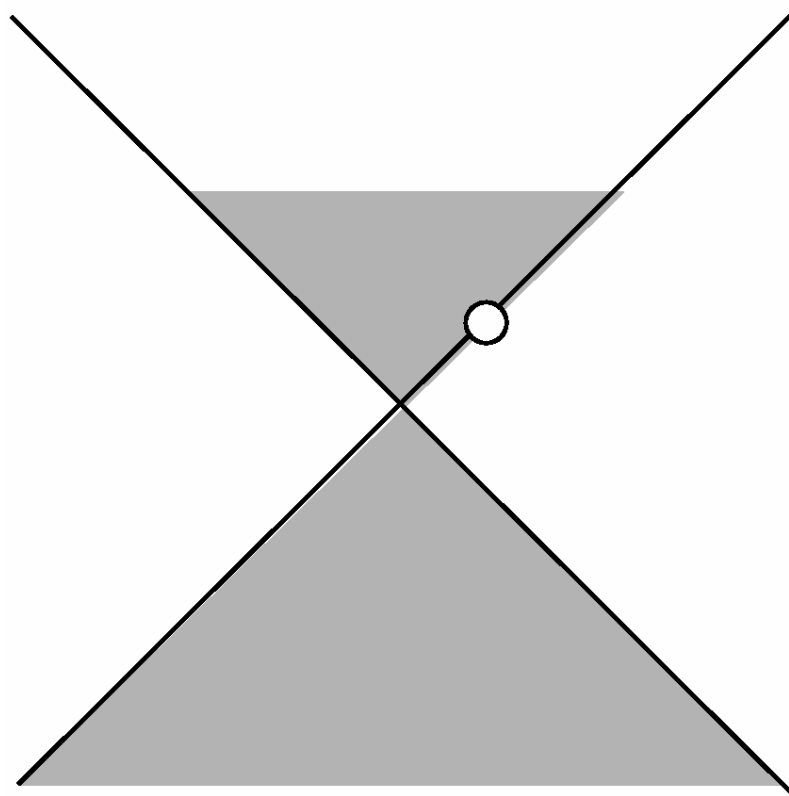
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# Imaginary part of the self energy (decay rate)

Decay rate of a **hole** via e-e interactions?



## Electron energy loss function

$\text{Im} \left[ \frac{1}{\varepsilon(q, \omega)} \right]$  is non-zero when

$$\text{Im} \varepsilon(q, \omega) \neq 0$$

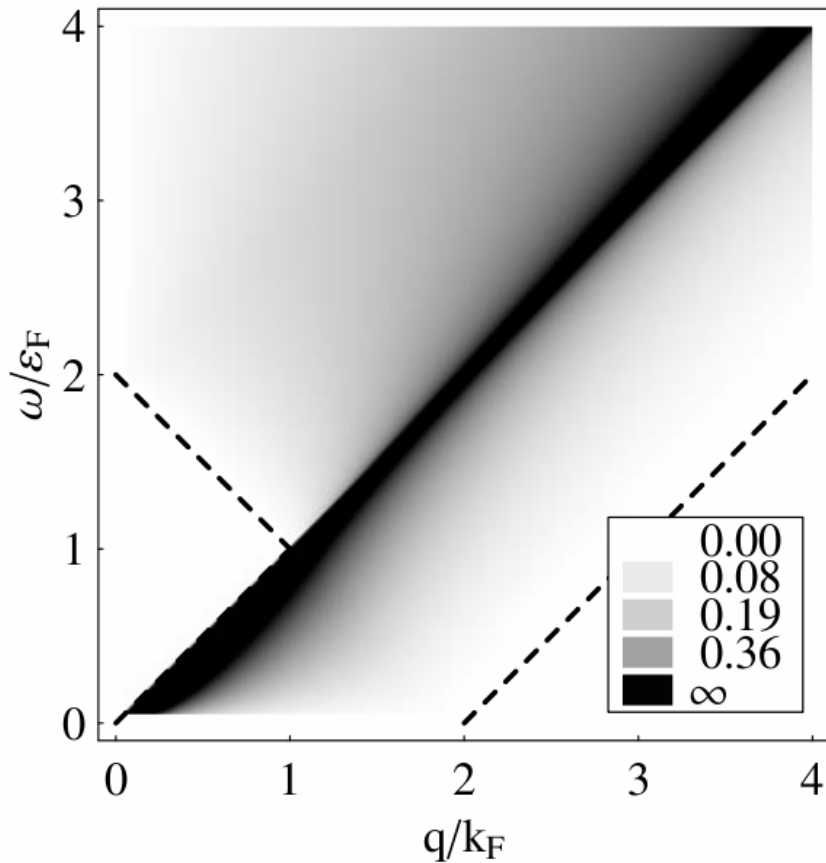
Electron-hole pair generation

$$\begin{cases} \text{Re} \varepsilon(q, \omega) = 0 \\ \text{Im} \varepsilon(q, \omega) = 0 \end{cases}$$

Plasmon emission

# Energy loss function of $n$ -doped graphene

$$-\text{Im } \varepsilon(q, \omega)$$



$$\text{Im} \left[ \frac{1}{\varepsilon(q, \omega)} \right]$$

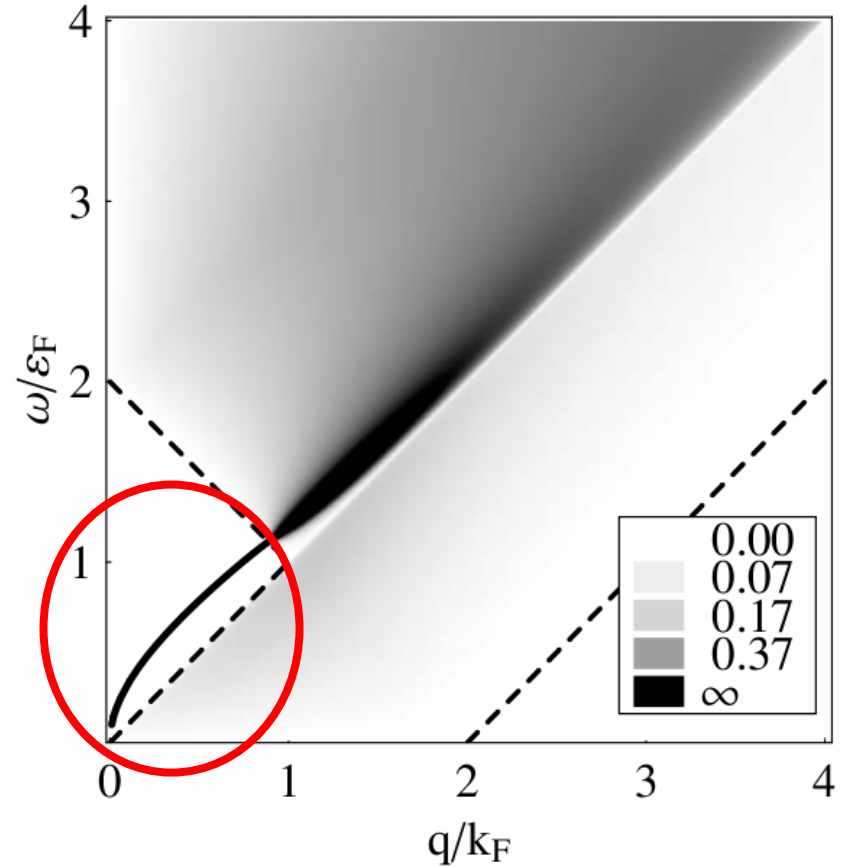


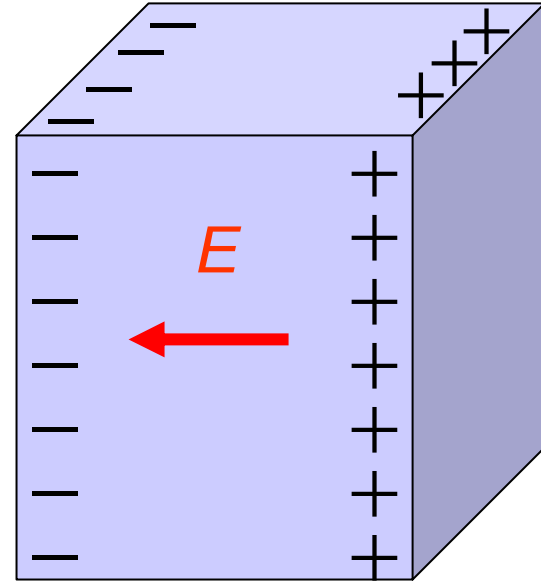
Figure taken from M. Polini *et al.*, PRB 77, 081411 (2008)

# Plasmons (oscillation w/o external field) in 3D & 2D

$$\omega_{\text{plasmon}}(q = 0)$$

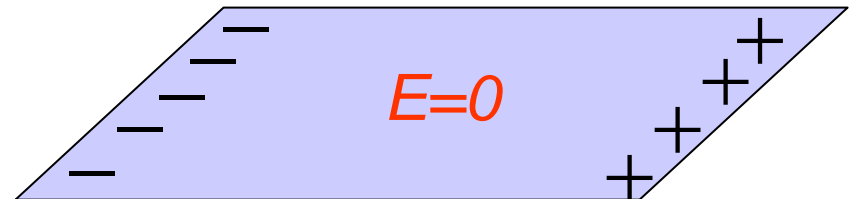
3D: finite restoring force

$$\omega_{\text{plasmon}}^{3\text{D}}(q = 0) \neq 0$$



2D: zero restoring force

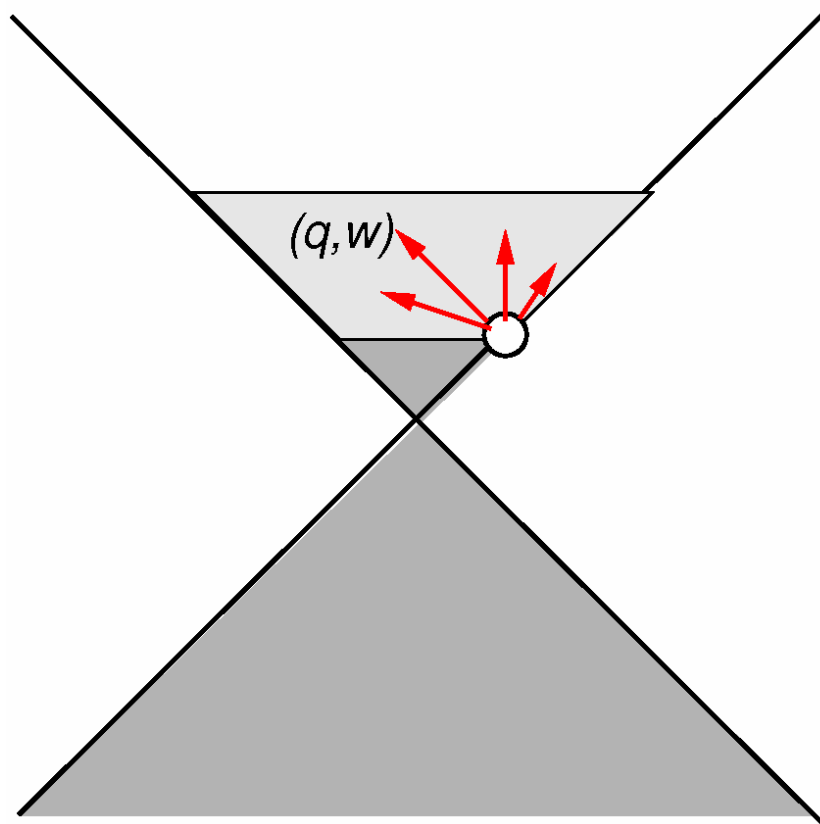
$$\omega_{\text{plasmon}}^{2\text{D}}(q = 0) = 0$$



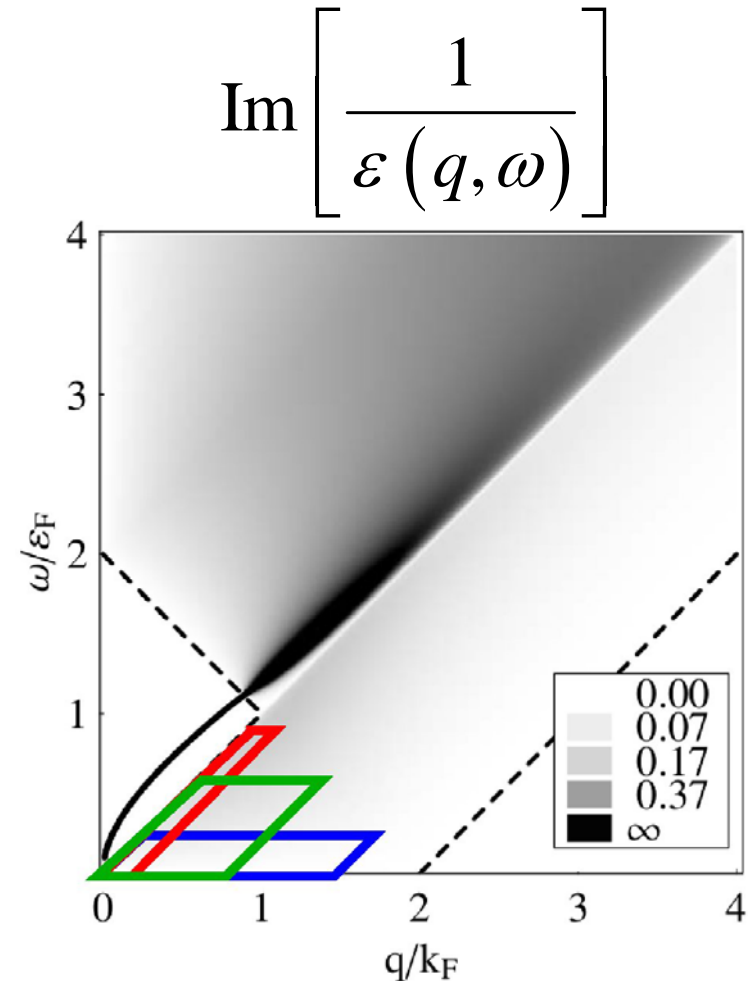
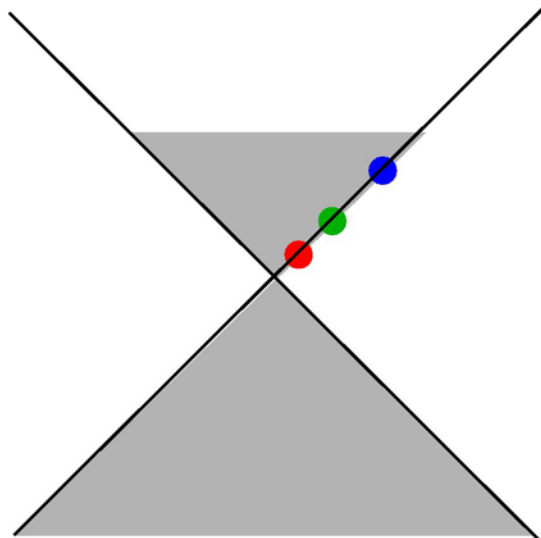
# Imaginary part of the self energy (decay rate)

Decay rate of a **hole** via e-e interactions?

$$\text{Im} \left[ \frac{1}{\varepsilon(q, \omega)} \right]$$



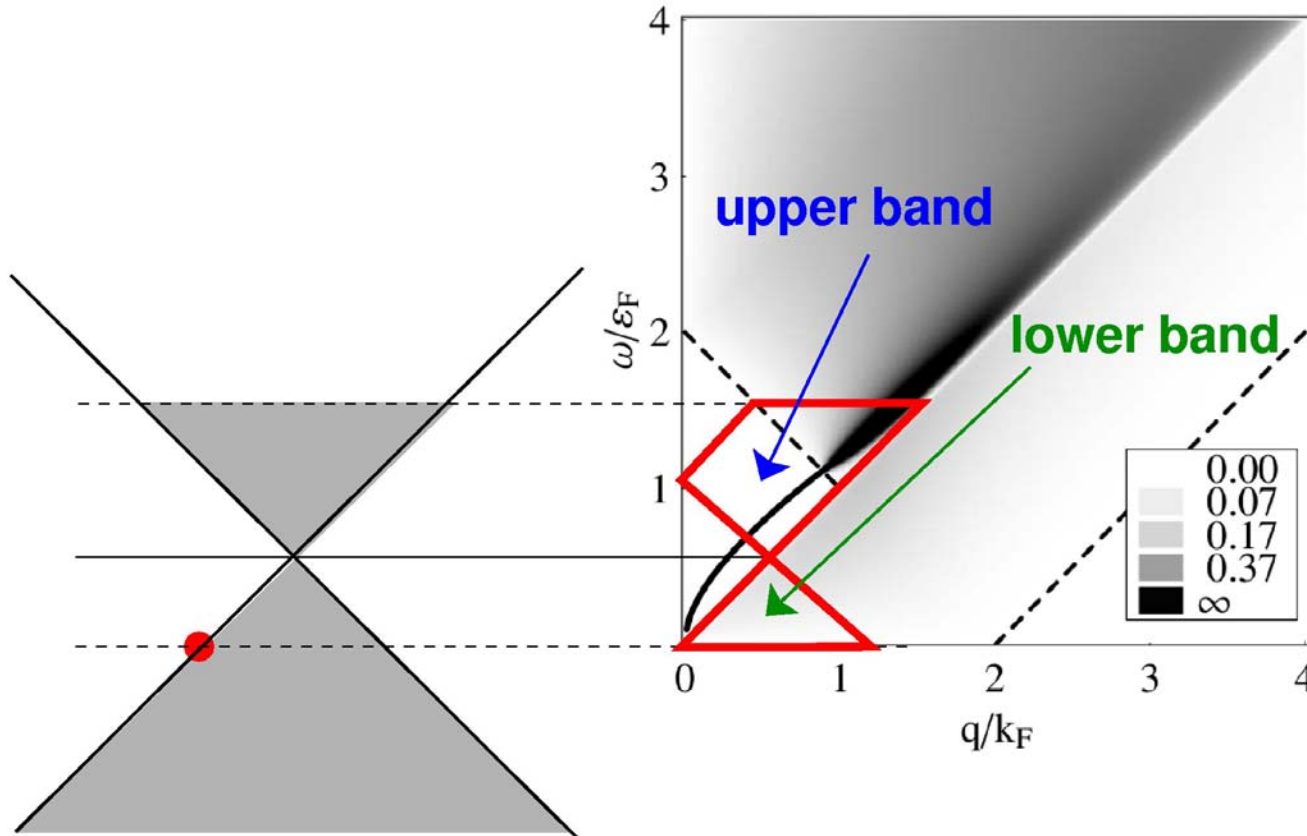
# Energy loss function and decay rate



- In *n*-doped graphene, a hole above the Dirac point energy do not decay by plasmon emission.

# Energy loss function and decay rate

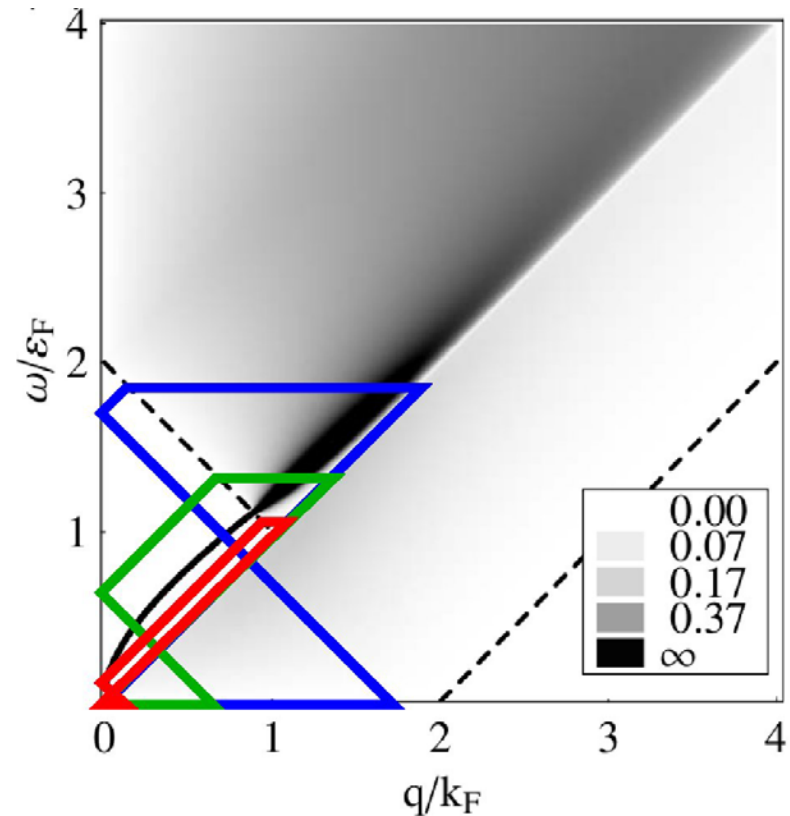
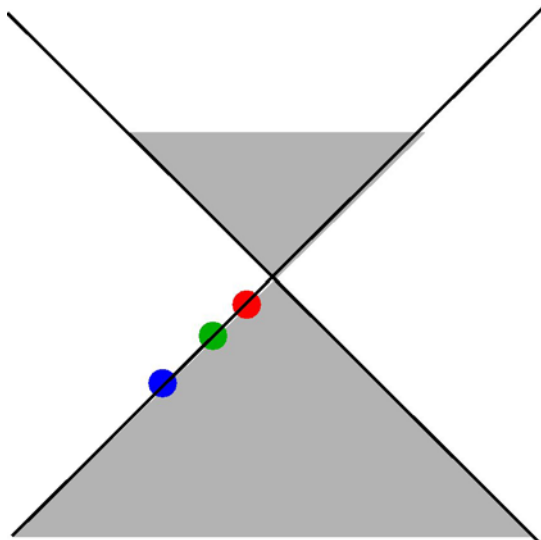
$$\text{Im} \left[ \frac{1}{\varepsilon(q, \omega)} \right]$$



- In  $n$ -doped graphene, a hole below the Dirac point energy **can decay by plasmon emission** (transition into upper band).
- Transition into lower band does not involve plasmons.

# Energy loss function and decay rate

$$\text{Im} \left[ \frac{1}{\varepsilon(q, \omega)} \right]$$



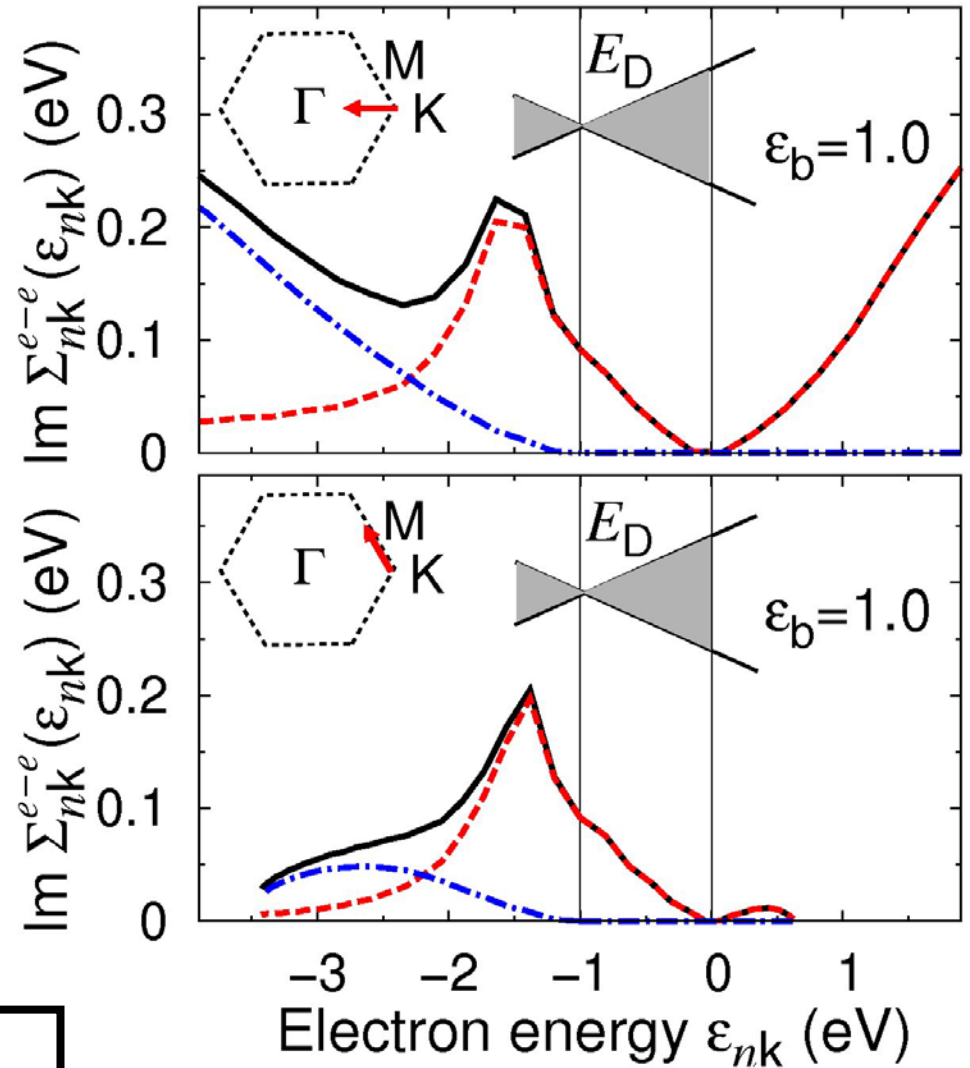
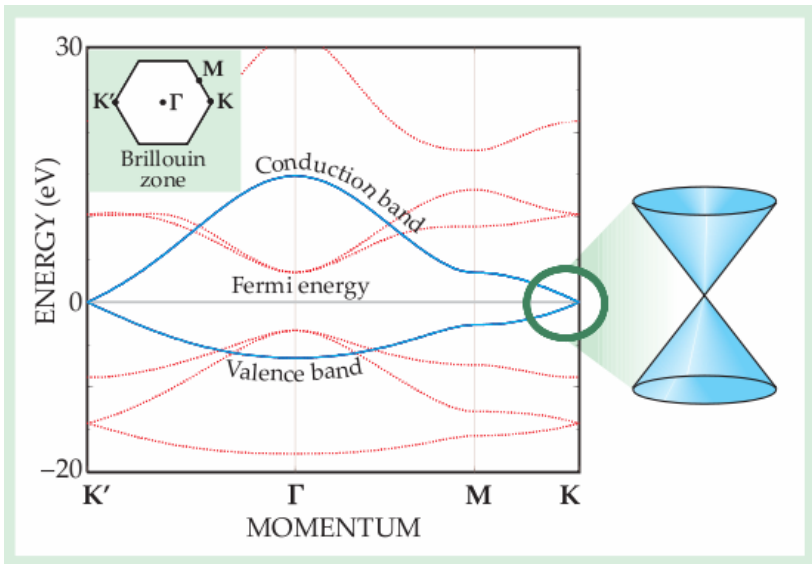
- An **optimal energy** exists for **transitions into upper band** having the largest plasmon contribution.



# Imaginary part of the electron self energy (e-e interactions)

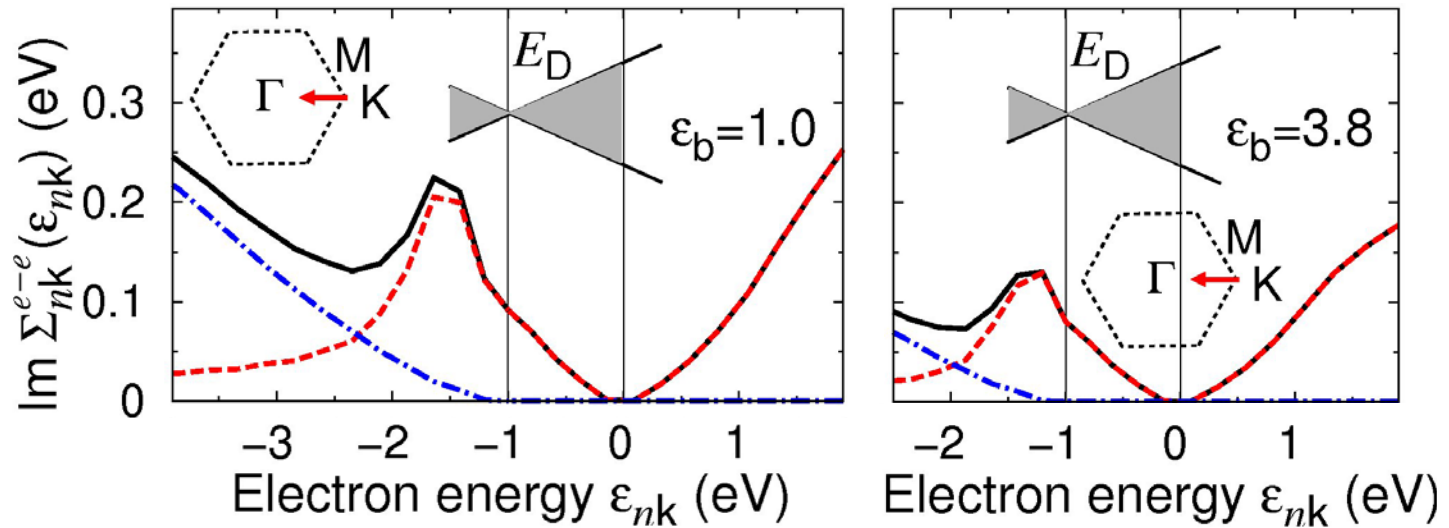
$$\text{Im} \Sigma_{\mathbf{k}}^{e-e}(\epsilon_{\mathbf{k}})$$

- Total decay rate
- - - Decay into upper band
- . - . Decay into lower band



In agreement with previous argument  
 Strong anisotropy: **van Hove singularity**

# Background screening effect



Substrate dielectric screening reduces the decay rate. Also, the plasmon induced peak position is shifted.

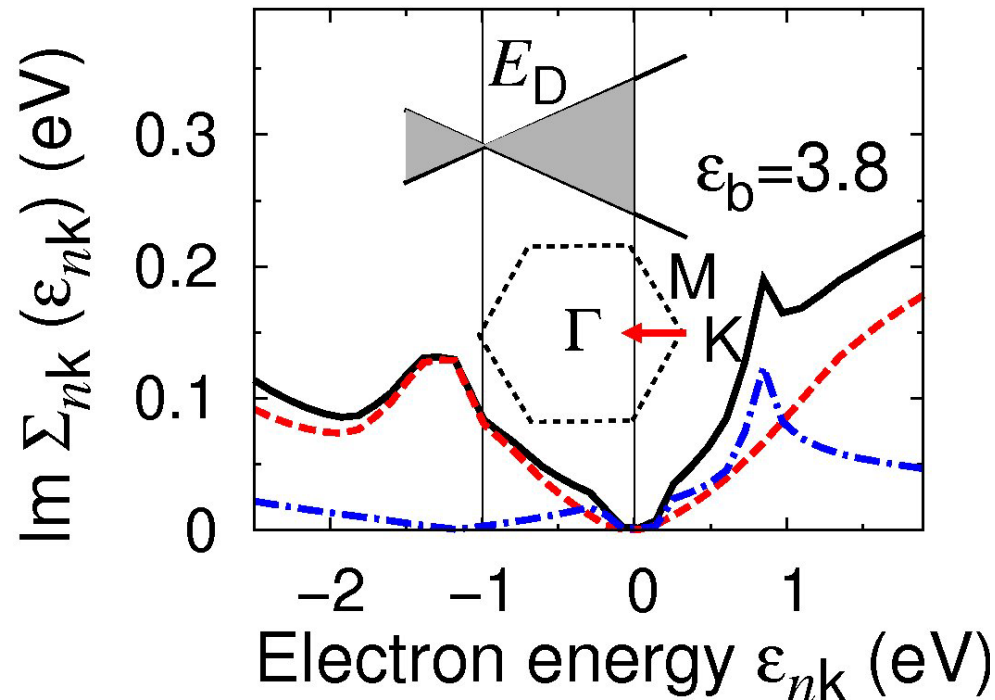
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# Electron self energy arising from e-e and e-ph interactions

$$\text{Im } \Sigma_{\mathbf{k}}(\varepsilon_{\mathbf{k}})$$

- Total self energy
- - - Self energy arising from e-e interactions
- . - . Self energy arising from e-ph interactions



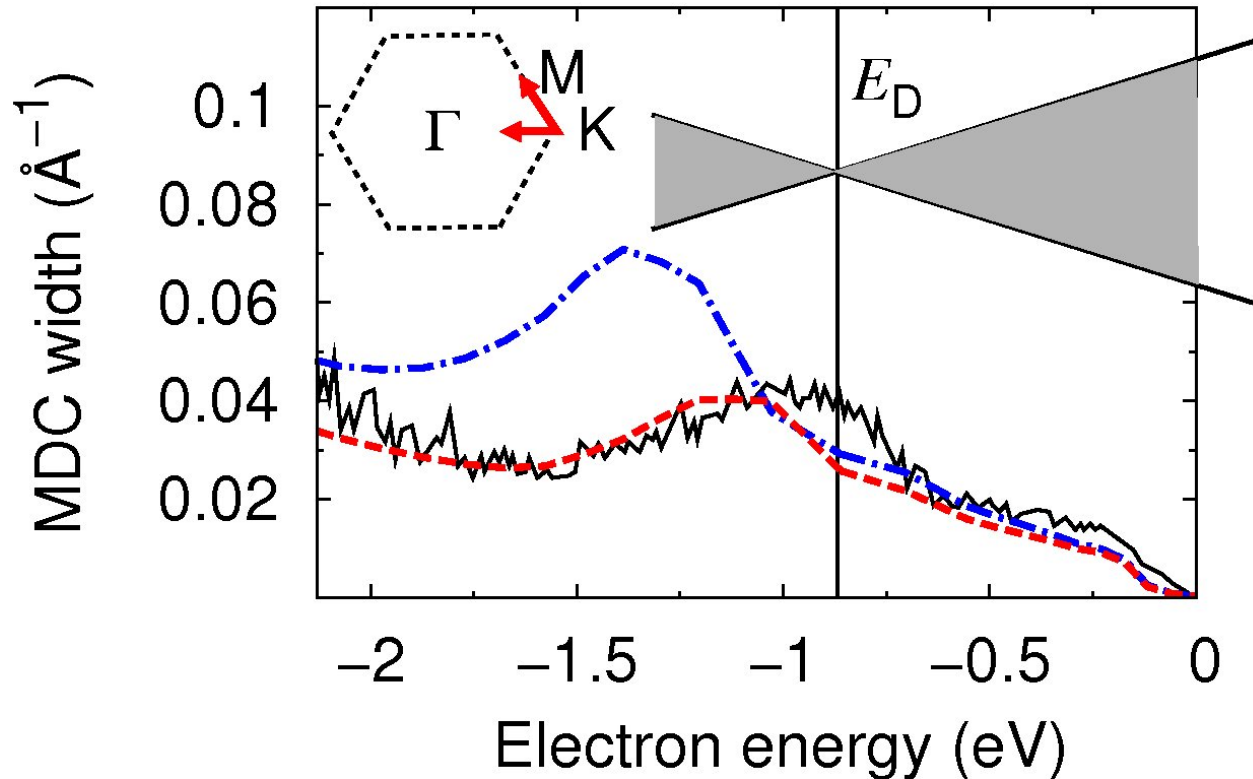
The two interactions are **comparable** near the Fermi energy.

# MDC width arising from e-e and e-ph interactions

———— Bostwick et al., Nature Phys. 3, 36 (2007)

- - - - Graphene with model substrate screening

- . - . Suspended graphene



Reasonable agreement between theory (substrate screening) and experiment  
Lower than measurements near the Dirac point energy: midgap states?

# Interpretation of the ARPES spectra of graphene

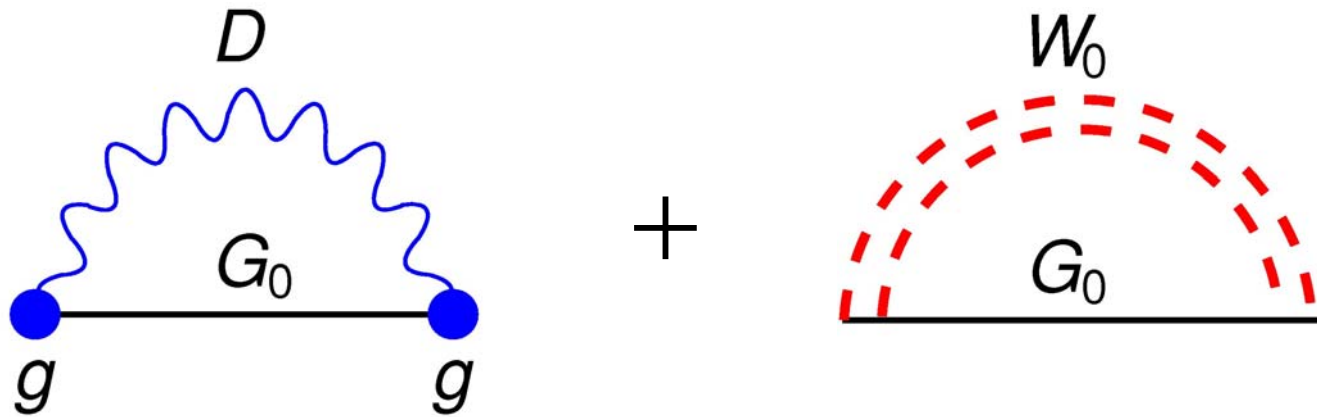
Q: Self-energy effects<sup>1</sup> or substrate induced band gap<sup>2</sup>?

A: Both are important.

- 1) A. Bostwick, *et. al.*, Nature Physics **3**, 36 (2007).
- 2) S.Y. Zhou, *et. al.*, Nature Materials **6**, 770 (2007).

# Summary

## First-principles calculations



→ Insights to interpret ARPES spectra of graphene